TOSHIBA Photocoupler GaAłAs IRED + Photo IC

TLP701

Industrial inverters Inverter for air conditioners IGBT/Power MOS FET gate drive

TLP701 consists of a GaA{As light-emitting diode and an integrated photodetector.

This unit is 6-lead SDIP package. The TLP701 is 50% smaller than the 8-pin DIP and meets the reinforced insulation class requirements of international safety standards. Therefore the mounting area can be reduced in equipment requiring safety standard certification.

The TLP701 is suitable for gate driving circuits for IGBTs or power MOSFETs. In particular, the TLP701 is capable of "direct" gate driving of low-power IGBTs.

- Peak output current : ±0.6 A (max)
- Guaranteed performance over temperature : −40 to 100°C
- Supply current

: 2 mA (max)

: 700 ns (max)

: ±10 kV/µs (min)

: 5000 Vrms (min)

 $: I_{FLH} = 5 \text{ mA} (\text{max})$

- Power supply voltage : 10 to 30 V
- Threshold input current
- Switching time (tpLH / tpHL)
- Common mode transient immunity
- Isolation voltage
- Construction mechanical rating

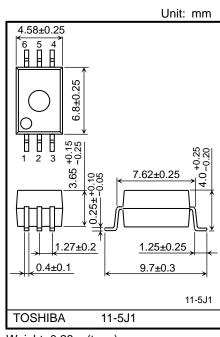
	7.62-mm pitch standard type	10.16-mm pitch TLPXXXF type
Creepage Distance	7.0 mm (min)	8.0 mm (min)
Clearance	7.0 mm (min)	8.0 mm (min)
Insulation Thickness	0.4 mm (min)	0.4 mm (min)

- UL approved : UL1577, File No. E67349
- c-UL approved :CSA Component Acceptance Service No. 5A, File No.E67349
- Option (D4)
 - VDE approved : EN60747-5-5 EN60065 EN60950-1 (Note 1) EN62368-1(Pending) (Note1)

(Note1) When a EN60747-5-5 approved type is needed, please designate the "Option(D4)"

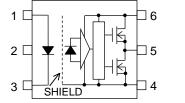
Truth Table

Input	LED	Tr1	Tr2	Output
Н	ON	ON	OFF	Н
L	OFF	OFF	ON	L



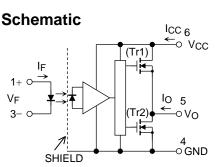
Weight: 0.26 g (typ.)

Pin Configuration (Top View)



1: ANODE 2: NC 3: CATHODE 4: GND 5: OUTPUT

6: VCC



A 0.1- μ F bypass capacitor must be connected between pins 6 and 4.

Start of commercial production 2004/04

Absolute Maximum Ratings (Ta = 25 °C)

	Characteristics		Symbol	Rating	Unit
	Forward current		lF	20	mA
	Forward current derating (Ta ≥ 85°C)		∆l _F /∆Ta	-0.54	mA/°C
	Pulse transient forward current	(Note 1)	IFP	1	А
LED	Reverse voltage		VR	5	V
	Input power dissipation		PD	40	mW
	Input power dissipation derating (Ta \ge 85°	ΔΡ _D /ΔTa	-1.0	mW/°C	
	Junction temperature	Tj	125	°C	
	"H" peak output current	(Note 2)	IOPH	-0.6	А
	"L" peak output current	(Note 2)	IOPL	0.6	А
'n	Output voltage		Vo	35	V
Detector	Supply voltage		Vcc	35	V
ď	Output power dissipation		PO	400	mW
	Output power dissipation derating (Ta \ge 85	ö°C)	ΔP _o /ΔTa	-1.0	mW/°C
	Junction temperature		Tj	125	°C
Oper	ating frequency	(Note 3)	f	25	kHz
Oper	Operating temperature range		Topr	-40 to 100	°C
Stora	Storage temperature range		Tstg	-55 to 125	°C
Lead	soldering temperature (10 s)	(Note 4)	Tsol	260	°C
Isola	Isolation voltage (AC, 60 s, R.H. ≤ 60%) (Note 5)			5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note: A ceramic capacitor (0.1 µF) should be connected from pin 6 to pin 4 to stabilize the operation of the high gain linear amplifier. Failure to provide the bypassing may impair the switching property. The total lead length between capacitor and coupler should not exceed 1 cm.
- Note 1: Pulse width $P_W \le 1 \mu s$, 300 pps
- Note 2: Exponential waveform pulse width $P_W \leq 2~\mu s,~f \leq \!\! 15~kHz$
- Note 3: Exponential waveform I_{OPH} \leq -0.3 A (\leq 2 µs), I_{OPL} \leq +0.3 A (\leq 2 µs), Ta =100 °C
- Note 4: For the effective lead soldering area
- Note 5: Device considered a two-terminal device: pins 1, 2 and 3 paired with pins 4, 5 and 6 respectively.

Recommended Operating Conditions

Characteristics		Symbol	Min	Тур.	Max	Unit
Input current, ON	(Note 6)	IF (ON)	7.5	_	10	mA
Input voltage, OFF		VF (OFF)	0	_	0.8	V
Supply voltage		Vcc	10	_	30	V
Peak output current		IOPH / IOPL	_	_	± 0.2	А
Operating temperature		Topr	-40	_	100	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Note 6: Input signal rise time (fall time) $< 0.5 \ \mu s$.

Electrical Characteristics (Ta = -40 to 100 °C, unless otherwise specified)

Characteristics		Symbol	Test Circuit	Test Condition		Min	Тур.*	Max	Unit
Forward voltage		VF	_	I _F = 5 mA, Ta = 25 °C		_	1.55	1.70	V
Temperature coefficient of forward voltage		∆V _F /∆Ta	_	$I_F = 5 \text{ mA}$	$I_F = 5 \text{ mA}$		-2.0	_	mV/°C
Input reverse current		IR	_	$V_R = 5 V$, $Ta = 25$	°C	_	—	10	μA
Input capacitance		CT	_	V = 0 V, $f = 1 MHz$, Ta = 25 °C	_	45	_	pF
	"H" Level	IOPH1	1	V _{CC} = 15 V	V6-5 = 4 V	—	-0.38	-0.2	A
Output current (Note 7)		I _{OPH2}		$I_F = 5 \text{ mA}$	V6-5 = 10 V	-	-0.60	-0.4	
	"L" Level	IOPL1	2	V _{CC} = 15 V I _F = 0 mA	V5-4 = 2 V	0.2	0.36	_	
	L Levei	IOPL2			V5-4 = 10 V	0.4	0.62	_	
Output voltogo	"H" Level	Vон	3	V _{CC} = 10 V	$\begin{array}{l} I_O = -100 \text{ mA}, \\ I_F = 5 \text{ mA} \end{array}$	6.0	8.5	_	- V
Output voltage	"L" Level	V _{OL}	4		$\begin{array}{l} I_O=100 \text{ mA},\\ V_F=0.8 \text{ V} \end{array}$	_	0.4	1.0	
Quartersat	"H" Level	Іссн	5	V _{CC} = 10 to 30 V	I _F = 10 mA	-	1.4	2.0	
Supply current	"L" Level	ICCL	6	V _O =Open	$I_F = 0 \text{ mA}$		1.3	2.0	mA
Threshold input current	$L\toH$	IFLH	_	V _{CC} = 15 V, V _O > 1 V		_	2.5	5	mA
Threshold input voltage	$H\toL$	VFHL	—	V _{CC} = 15 V, V _O < 1 V		0.8	—	_	V
Supply voltage	V _{CC} — —		10	—	30	V			

(*): All typical values are at $Ta = 25^{\circ}C$

Note: This product is more sensitive than conventional products to electrostatic discharge (ESD) owing to its low power consumption design. It is therefore all the more necessary to observe general precautions regarding ESD when handling this component.

Note 7: Duration of IO time \leq 50 µs, 1 pulse

Isolation Characteristics (Ta = 25 °C)

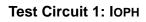
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit	
Capacitance input to output	Cs	Vs = 0 V , f = 1MHz (Ne	lote 5)	_	1.0	_	pF
Isolation resistance	Rs	R.H. ≤ 60 %, Vs = 500 V (N	lote 5)	1×10 ¹²	10 ¹⁴	_	Ω
	BVs	AC, 60 s		5000	_	_	Vana
Isolation voltage		AC, 1 s, in oil		_	10000	_	Vrms
		DC, 60 s, in oil		_	10000	_	Vdc

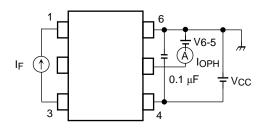
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Switching Characteristics (Ta = -40 to 100 °C, unless otherwise specified)

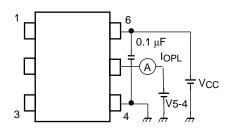
Characteristics		Symbol	Test Circuit	Test Condition		Min	Typ.*	Max	Unit
Propagation delay time	$L\toH$	tpLH		V/	$I_F=0\to 5\ mA$	100	_	700	
	$H \rightarrow L$	tpHL			$I_F=5 \rightarrow 0 \ mA$	100	_	700	
Output rise time (10–90 %)		tr	7	$V_{CC} = 30 V$ $R_{g} = 47 \Omega$ $C_{g} = 3 nF$	$I_F=0 \rightarrow 5 \text{ mA}$	_	50	_	ns
Output fall time (90–10 %)		tf			$I_F=5 \rightarrow 0 \ mA$	_	50	_	
Switching time dispersion between ON and OFF		tpHL-tpLH	IF		I _F = 0 ⇔ 5 mA	_	_	500	
Common mode transient i at HIGH level output	mmunity	CMH		Vсм =1000 Vр-р	$\begin{array}{l} I_F=5 \text{ mA} \\ V_{O \ (min)}=26 \text{ V} \end{array}$	-10000	_	_	
Common mode transient immunity at LOW level output		CML	8	V _{CC} = 30 V Ta = 25 °C	I _F = 0 mA V _{O (max)} = 1 V	10000	_	_	V/μs

(*): All typical values are at Ta = 25 °C.

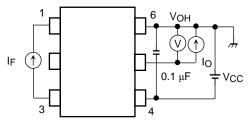




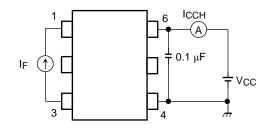
Test Circuit 2: IOPL

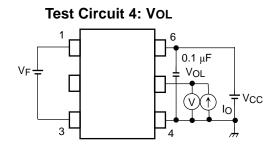


Test Circuit 3: VOн

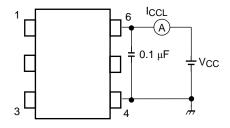


Test Circuit 5: ICCH

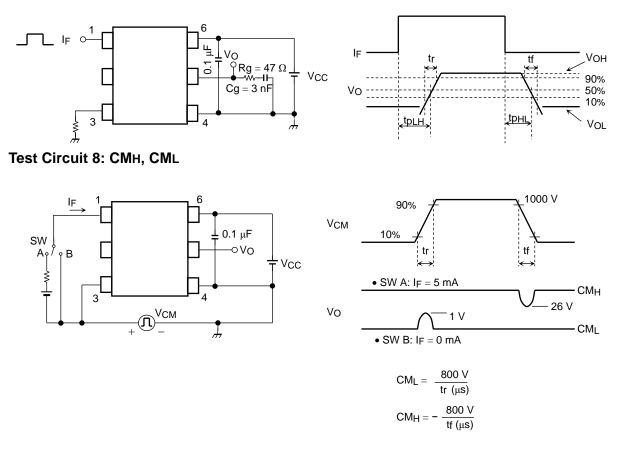




Test Circuit 6: ICCL



Test Circuit 7: tpLH, tpHL, tr, tf, PDD

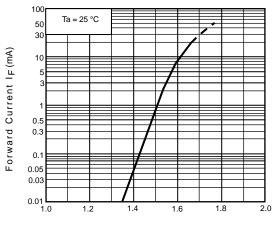


CM_L (CM_H) is the maximum rate of rise (fall) of the common mode voltage that can be sustained with the output voltage in the LOW (HIGH) state.

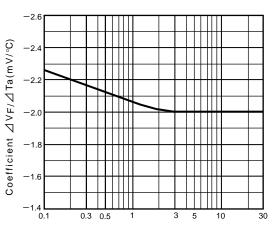
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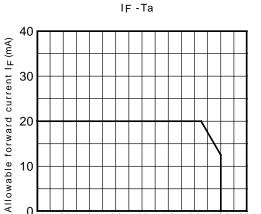




Forward Voltage VF(V)

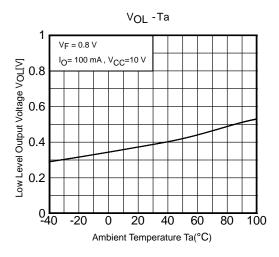


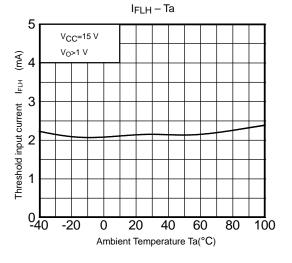
Forward Current I_F (mA)

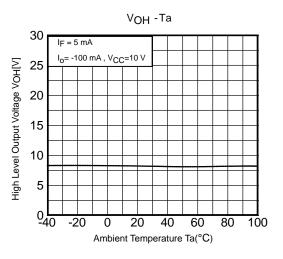




Ambient Temperature Ta(°C)

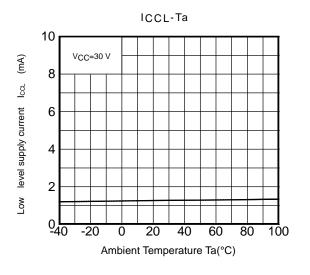


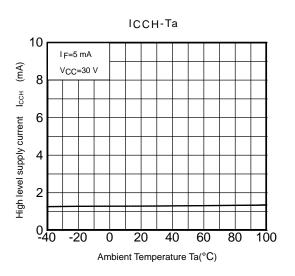




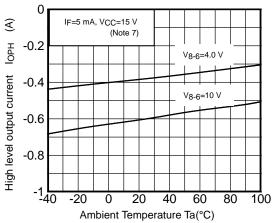
*: The above graphs show typical characteristics.

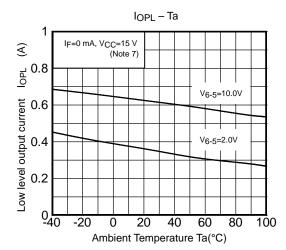
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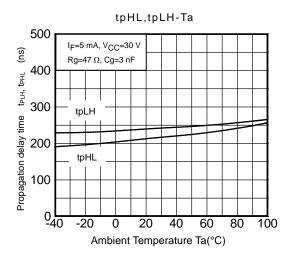












 $\ast :$ The above graphs show typical characteristics.

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